Hyperfast Rectifier 50 A, 600 V

RHRG5060-F085

Description

The RHRG5060-F085 is an hyperfast diode with softrecovery characteristics (trr < 45ns). It has half the recovery time of ultrafast diode and is of silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of automotive switching power supplies and other power switching automotive applications. Its low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistors.

Features

- High Speed Switching ($t_{rr} = 45 \text{ ns (Typ.)} @ I_F = 50 \text{ A}$)
- Low Forward Voltage($V_F = 1.67 \text{ V (Typ.)} @ I_F = 50 \text{ A}$)
- Avalanche Energy Rated
- AEC-Q101 Qualified
- This Device is Pb-Free

Applications

- Switching Power Supply
- Power Switching Circuits
- General Purpose
- Automotive and General Purpose

ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	600	V
Working Peak Reverse Voltage	V_{RWM}	600	V
DC Blocking Voltage	V _R	600	V
Average Rectified Forward Current @ T _C = 25 °C	I _{F(AV)}	50	Α
Non-repetitive Peak Surge Current (Halfwave 1 Phase 50 Hz)	I _{FSM}	150	Α
Avalanche Energy (1.4 A, 40 mH)	E _{AVL}	40	mJ
Operating Junction and Storage Temperature	T _{J,} T _{STG,}	–55 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



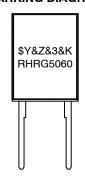
ON Semiconductor®

www.onsemi.com

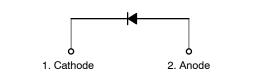


TO-247-2L 340CL

MARKING DIAGRAM



\$Y	= ON Semiconductor Logo
& <i>7</i>	= Assembly Plant Code
83	= Numeric Date Code
&K	= Lot Code
RHRG5060	= Specific Device Code



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

THERMAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Sy	ymbol	Parameter	Max	Units
F	$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	0.42	°C/W
F	$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	45	°C/W

PACKAGE MARKING AND ORDERING INFORMATION

Device Marking	Device	Package	Tube	Quantity
RHRG5060	RHRG5060-F085	TO-247	-	30

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
I _R	Instantaneous Reverse Current	V _R = 600 V	T _C = 25°C	-	-	250	uA
			T _C = 175°C	-	-	1.5	mA
V _{FM}	Instantaneous Forward Voltage	I _F = 50 A	T _C = 25°C	-	1.67	2.1	V
(Note 1)	(Note 1)		T _C = 175°C	-	1.29	1.7	V
t _{rr} (Note 2)	The second control of	$I_F = 1 \text{ A}, \\ di/dt = 100 \text{ A}/\mu\text{s}, \\ V_{CC} = 390 \text{ V}$	T _C = 25°C	_	37	45	ns
		I _F = 50 A, di/dt = 100 A/μs,	$T_C = 25^{\circ}C$	-	45	60	ns
		$V_{CC} = 390 \text{ V}$	T _C = 175°C	-	200	-	ns
ta tb Q _{rr}	Reverse Recovery Time Reverse Recovery Charge	$I_F = 50 \text{ A}, \\ \text{di/dt} = 100 \text{ A/}\mu\text{s}, \\ \text{V}_{CC} = 390 \text{ V}$	T _C = 25°C	_	25 20 45	1 1 1	ns ns nC

^{1.} Pulse : Test Pulse width = 300 μ s, Duty Cycle = 2%

2. Guaranteed by design
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TEST CIRCUITS AND WAVEFORMS

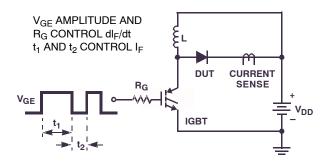


Figure 1. T_{rr} Test Circuit

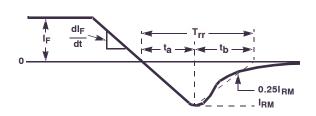


Figure 2. T_{rr} Waveforms and Definitions

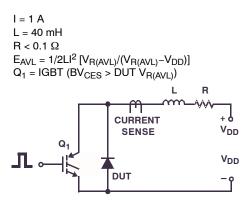


Figure 3. Avalanche Energy Test Circuit

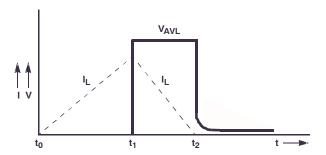


Figure 4. Avalanche Current and Voltage Waveforms

TYPICAL PERFORMANCE CHARECTERISTICS

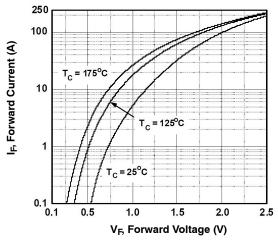


Figure 5. Typical Forward Voltage Drop vs. Forward Current

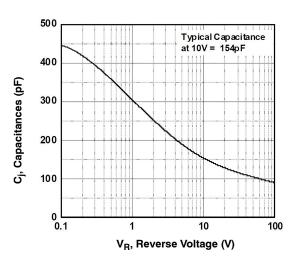


Figure 7. Typical Junction Capacitance

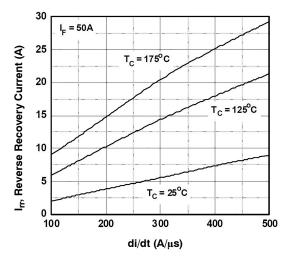


Figure 9. Typical Reverse Recovery Current vs. di/dt

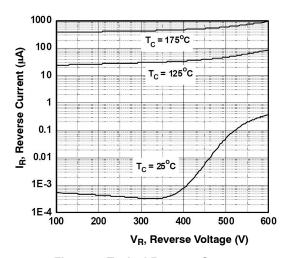


Figure 6. Typical Reverse Current vs. Reverse Voltage

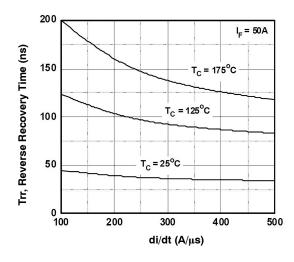


Figure 8. Typical Reverse Recovery Time vs. di/dt

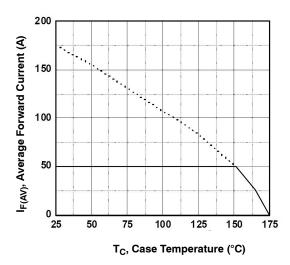


Figure 10. Forward Current Derating Curve

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

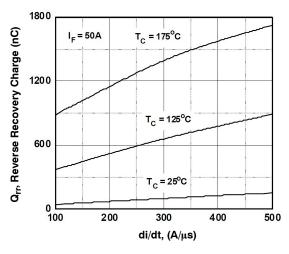


Figure 11. Reverse Recovery Charge

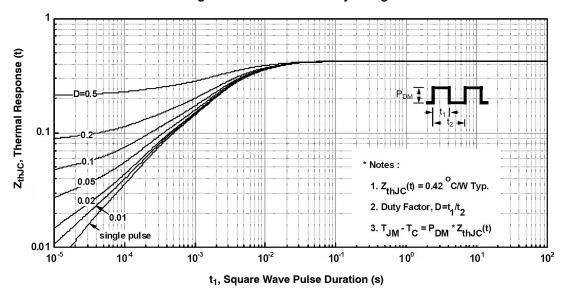
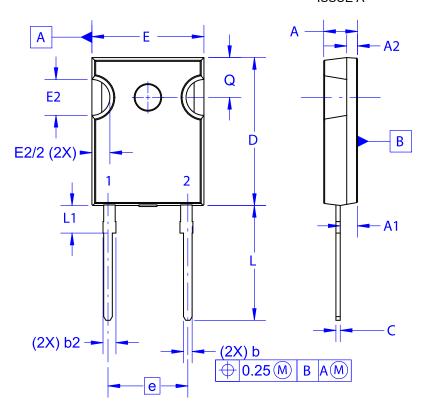


Figure 12. Transient Thermal Response Curve

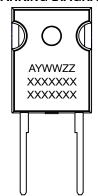
TO-247-2LD CASE 340CL **ISSUE A**





- A. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DRAWING CONFORMS TO ASME Y14.5 2009.
 D. DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED BY L1.
- E. LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY L1.

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code

= Assembly Location

= Year

WW = Work Week

= Assembly Lot Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

	DATE 03 DEC 2019		
Ø P —			Ø P1 D2
E1 —		1	D1
,			9

DIM	MILLIMETERS			
	MIN	NOM	MAX	
Α	4.58	4.70	4.82	
A1	2.29	2.40	2.66	
A2	1.30	1.50	1.70	
b	1.17	1.26	1.35	
b2	1.53	1.65	1.77	
С	0.51	0.61	0.71	
D	20.32	20.57	20.82	
D1	16.37	16.57	16.77	
D2	0.51	0.93	1.35	
Е	15.37	15.62	15.87	
E1	12.81	~	~	
E2	4.96	5.08	5.20	
е	~	11.12	~	
L	15.75	16.00	16.25	
L1	3.69	3.81	3.93	
ØΡ	3.51	3.58	3.65	
Ø P 1	6.61	6.73	6.85	
Q	5.34	5.46	5.58	
S	5.34	5.46	5.58	

DOCUMENT NUMBER:	98AON13850G	Electronic versions are uncontrolled except when accessed directly from the Document Repositor Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	TO-247-2LD		PAGE 1 OF 1	

ON Semiconductor and un are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

ON Semiconductor and the are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor and see no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Email Requests to: orderlit@onsemi.com

ON Semiconductor Website: www.onsemi.com

TECHNICAL SUPPORT North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative